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Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.450 inches	
End Application:	
1425-01-066-7775	
Mounting Facility Quantity:	
1	
Joint Electronic Device Engineering Council/jedec/case Ou	Itline Designation:
Do-5	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed case	
Overall Width Across Flats:	
0.687 inches	
Thread Size:	
0.250 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
10.5 breakdown voltage, dc	
Current Rating Per Characteristic:	
24.00 amperes forward current, average peak	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bul	letins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, a	nd similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditio	ns that are shown as "typical", "average", "", etc.).
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
1 tab, solder lug and 1 threaded stud	
Specification Data:	
81349-mil-s-19500/358 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	